NSN 5962-01-379-0093

Memory Microcircuit - Page 1 of 2



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Between 1.380 inches and 1.420 inches

Body Width:

Between 0.584 inches and 0.604 inches

Body Height:

0.280 inches

Maximum Power Dissipation Rating:

4.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

5975-01-253-6144 junction box

Features Provided:

Static operation and high impedance and w/disable and w/enable and bidirectional

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

25 input

Current Rating Per Characteristic:

150.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

20.00 input picofarads and 22.00 output picofarads

Time Rating Per Chacteristic:

200.00 nanoseconds access

Memory Device Type:

Ram

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

NSN 5962-01-379-0093

Memory Microcircuit - Page 2 of 2



Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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